

Amendments to the Specification

Please replace paragraph [0020] with the following amended paragraph:

[0020] Figure 2 further illustrates a porous interlayer dielectric (ILD), such as ILD 215, which is disposed on underlying layer 205. ILD 215 may be formed from any one of a plurality of known dielectric materials. As an illustrative example ILD 215 may be an oxide/spin-on glass. Some examples of oxide dielectrics include: LKD-5109, which may be obtained from JSR CORPORATION; ~~Nanoglass-E~~ NANOGLASS® E, which may be obtained from ~~Honeywell~~ HONEYWELL INTERNATIONAL INC.; and ~~Zirkon~~ ZIRKON®, which may be obtained from ~~Shipley~~ SHIPLEY COMPANY LLC. As another illustrative example, ILD 215 may be a polymer. Some examples of polymer dielectrics are porous silk, which may be obtained from ~~Dow Chemical~~ DOW CHEMICAL COMPANY and GX-3P, which may be obtained from ~~Honeywell~~ HONEYWELL INTERNATIONAL INC.